

AFEM-9206 Multiband Multimode Module

Description

The Broadcom[®] AFEM-9206 is a multiband multimode module which includes PAs, duplexers, an ANT switch, a coupler, and an LNA. This module supports bands 1, 2/25, 3, 4/66, 39, 7, 30, 40, 41 and BC1. In addition, B21Rx and B34 can be supported with an external filter. The AFEM-9206 is designed to support ET (envelope tracking) for FDD bands and TDD bands, and the part can support various CA (carrier aggregation).

Input and output terminals are internally matched to 50Ω . The power amplifier is manufactured on an advanced InGaP HBT technology offering state-of-the-art reliability, temperature stability, and ruggedness. This module is housed in a cost effective, extremely small and thin package.

Reliability Prediction Model

Failure rate predictions are based on AFEM-9206 HTOL test results. The prediction uses an exponential cumulative failure function (constant failure rate) as the reliability prediction model to predict failure rate and mean time to failure (MTTF) at various temperatures as shown in Table 2. The wear-out mechanisms are not considered. The Arrhenius temperature derating equation is used. Broadcom assumes no failure mechanism change between stresses and use conditions. Bias and temperature are alterable stresses and must be considered with the thermal resistance of the devices when determining the stress condition. The failure rate will have a direct relationship to the life stress. The failure rate prediction was calculated using activation energy of 1.33eV as a conservative estimate. Confidence intervals are based upon the chisquared prediction method associated with exponential distribution.

Table 1: Life Prediction: Demonstrated Performance

Test Name	Stress Condition	Total Units Tested	Total Device Hours	Number of Failed Units
High Temperature Operating Life	Tj = 150°C, RF bias	75	37,800 hours	0/75

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Table 2: Estimated for Various Channel Temperatures

Channel Temperature (°C)	Point Typical Performance MTTF (Years/Failure)	90% Confidence MTTF (Years)	Point Typical Performance FIT	90% Confidence FIT
150	4.31	1.87	26,455.03	60978.84
125	42.67	18.51	2673.76	6163.02
100	573.97	249.01	198.75	458.12
85	3249.79	1409.89	35.10	80.91
60	82,706.38	35,881.29	1.38	3.18

Point typical MTTF is simply the total device hours divided by the number of failures. Because no failures were observed, the point estimate is calculated under the assumption that one unit failed. FIT rates shown are relatively high due to the limited device hours at product release.

Table 3: Environmental Test Results

Stress	Conditions	Duration	Failures/Number Tested
High Temperature Storage	Ta = 150°C JESD22-A103	500 hours	0/75
Unbiased Highly Accelerated Temperature and Humidity Stress	130°C/85%RH, 205 kPa, no bias JESD22-A118	96 hours	0/75
Temperature Cycling	–65°C/+150°C, air to air JESD22-A104	500 cycles	0/75

Table 4: Operating Life Tests Results

Stress	Conditions	Duration	Failures/Number Tested
High Temperature Operating Life (HTOL)	Tj ≥ 150°C, VBATT=3.7V, Vcc=4.6V, PA CNTRL = HPM, middle frequency, maximum Pout into 50Ω JESD22-A108	500 hours	0/75
Temperature Humidity with Bias (THB)	Ta = 85° C/ 85° RH, VBATT=3.7V, Vcc=4.6V, RFFE PA CNTRL = power down mode, RF ports into 50Ω JESD22-A101	500 hours	0/75

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Table 5: Mechanical Tests Information

Stress	Conditions	Duration	Failures/Number Tested
Drop Test	Peak acceleration: 1500G, pulse duration: 0.5ms half-sine pulse. JESD22-B111	30 drops	0/60
Cycle Bending Test	Amplitude 1.0 mm, total displacement 2.0 mm. Bending rate 80 mm per minute.	5×	0/30
Bending Test	Bending up to 5 mm with 1-mm increment. Maintained in bend state for 5s ± 1s for every 1-mm increment. IEC60068-2-21	Every 1 mm, 5 mm	0/30
Shear Test	Force = 10N for 60 seconds, four sides separately. IEC60068-2-21	60 seconds/side	0/30

Table 6: Thermal Resistance Information

Stress	Product	Theta Jc
Thermal Resistance	Vbatt = 3.7V, Vcc = 3.3V; RFFE PA CNTRL= B25 (HPM)	16.2°C/W
Thermal Resistance	Vbatt = 3.7V, Vcc = 3.3V; RFFE PA CNTRL= B7 (HPM)	16.3°C/W
Thermal Resistance	Vbatt = 3.7V, Vcc = 3.1V; REEF PA CNTRL=B41H (HPM)	19.9°C/W

Table 7: ESD Ratings

ESD Test	Reference	Results
Human Body Model	JS-001	1250V (Class 1C)
Charge Device Model	JS-002	500V (Class C1)
Charge Device Model (RX RF ports)	JS-002	500V (Class C1)

HBM

Class 0A is ESD voltage level < 125V,

Class 0B is voltage level between 125V and 250V,

Class 1A is voltage level between 250V and 500V,

Class 1B is voltage level between 500V and 1000V,

Class 1C is voltage level between 1000V and 2000V,

Class 2 is voltage level between 2000V and 4000V,

Class 3A is voltage level between 4000V and 8000V,

Class 3B is voltage level ≥ 8000V.

CDM

Class C0a is ESD voltage level < 125V,

Class C0b is voltage level between 125V and 250V,

Class C1 is voltage level between 250V and 500V,

Class C2a is voltage level between 500V and 750V,

Class C2b is voltage level between 750V and 1000V,

Class 3 is voltage level ≥ 1000V.

Handling Precautions

NOTE: ESD sensitivity levels for Human Body Model and Charge Device Model make the following handling precautions necessary:

- 1. Ensure a Faraday cage or conductive shield is used during transportation processes.
- 2. If the static charge at the SMT assembly station is above device sensitivity level, place an ionizer near the device for charge neutralization.
- 3. Personal grounding must be worn at all times when handling the devices.

Moisture Sensitivity Classification: Level 3

Preconditioning per JESD22-A113-D Level 3 was performed on all devices prior to reliability testing except ESD and mechanical tests.

MSL3 preconditioning (JESD22-A113D): 125°C HTSL for 24 hours + 60°C/60% RH for 40 hours + 3XIR reflow, 260°C peak.

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